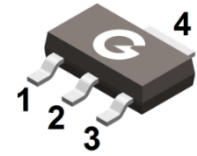
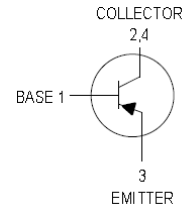


Features

- High saturation voltage
- Excellent h_{FE} linearity
- RoHS compliant with Halogen-free
- Qualified to AEC-Q101 Standards

HF



SOT-223

Mechanical Data

- Case: SOT-223
- Molding Compound: UL Flammability Classification Rating 94V-0
- Terminals: Matte tin-plated leads; solderability-per MIL-STD-202, Method 208

Ordering Information

Part Number	Package	Shipping Quantity	Marking Code
TFZT4030	SOT-223	4000 pcs / Tape & Reel	FZT4030

Maximum Ratings (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
Collector-Base Breakdown Voltage	V_{CBO}	-40	V
Collector-Emitter Breakdown Voltage	V_{CEO}	-40	V
Emitter-Base Breakdown Voltage	V_{EBO}	-6	V
Collector Current (Continuous)	I_C	-3	A
Collector Current (Peak)	I_{CM}	-5	A

Thermal Characteristics

Parameter	Symbol	Value	Unit
Power Dissipation ($T_A = 25^\circ\text{C}$) ^{*1}	P_D	2	W
Thermal Resistance Junction-to-Air ^{*1}	$R_{\theta JA}$	64	$^\circ\text{C/W}$
Thermal Resistance Junction-to-Case	$R_{\theta JC}$	20	$^\circ\text{C/W}$
Junction Temperature Range	T_J	-55 ~ +150	$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-55 ~ +150	$^\circ\text{C}$

Note 1: The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper

Electrical Characteristics (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = -100\mu\text{A}, I_E = 0$	-40	-	-	V
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = -10\text{mA}, I_B = 0$	-40	-	-	V
Collector-Emitter Sustaining Voltage	$V_{(BR)CEO(sus)}$	$I_C = -10\text{mA}, I_B = 0$	-40	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = -50\mu\text{A}, I_C = 0$	-6	-	-	V
Collector Cut-off Current	I_{CBO}	$V_{CB} = -40\text{V}, I_E = 0$	-	-	-0.1	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB} = -6\text{V}, I_C = 0$	-	-	-0.1	μA
DC Current Gain	h_{FE}	$V_{CE} = -1\text{V}, I_C = -0.5\text{A}$	220	-	-	-
		$V_{CE} = -1\text{V}, I_C = -1\text{A}$	200	-	400	-
		$V_{CE} = -1\text{V}, I_C = -3\text{A}$	100	-	-	-
Collector-emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = -500\text{mA}, I_B = -50\text{mA}$	-	-	-0.15	V
		$I_C = -1\text{A}, I_B = -0.1\text{A}$	-	-	-0.20	V
		$I_C = -3\text{A}, I_B = -0.3\text{A}$	-	-	-0.50	V
Base-emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = -1\text{A}, I_B = -0.1\text{A}$	-	-	-1.0	V
Base-emitter Voltage	$V_{BE(on)}$	$V_{CE} = -2\text{V}, I_C = -1\text{A}$	-	-	-1.0	V
Transition Frequency	f_T	$I_C = -0.5\text{A}, V_{CE} = -10\text{V}$ $f = 1\text{MHz}$	-	160	-	MHz
Output Capacitance	C_{ob}	$V_{CB} = -10\text{V}, I_E = 0\text{A}, f = 1\text{MHz}$	-	44	-	pF
Input Capacitance	C_{ib}	$V_{EB} = -5\text{V}, I_E = 0\text{A}, f = 1\text{MHz}$	-	161	-	pF

Ratings and Characteristics Curves (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

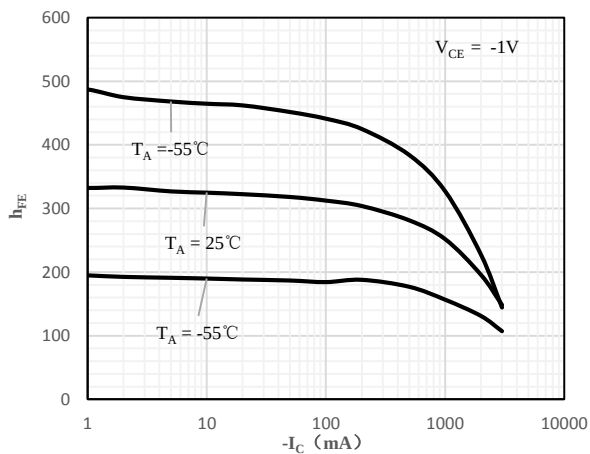


Fig 1 h_{FE} vs. I_C

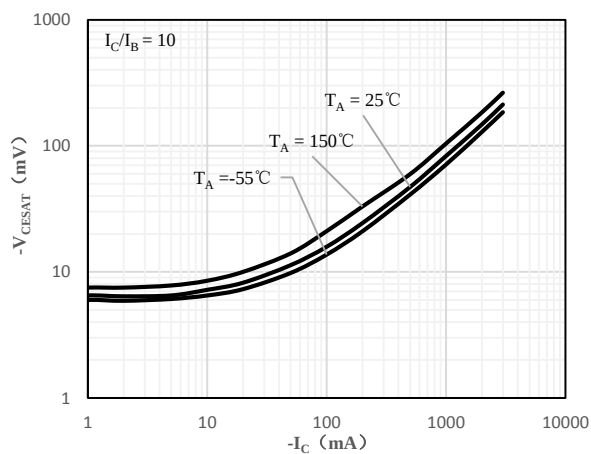


Fig 2 $V_{CE(sat)}$ vs. I_C

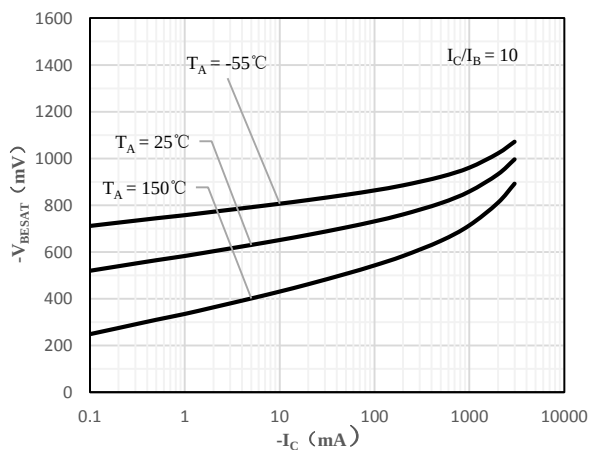


Fig 3 $V_{BE(sat)}$ vs. I_C

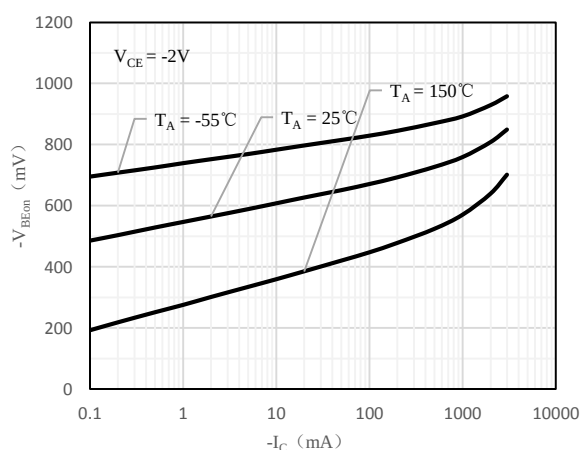


Fig 4 $V_{BE(on)}$ vs. I_C

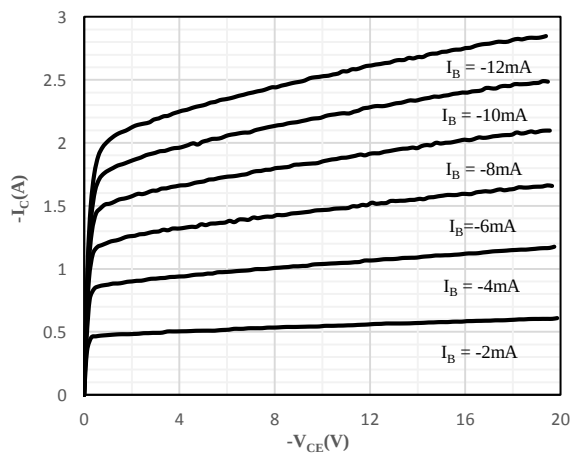


Fig 5 I_C vs. V_{CE}

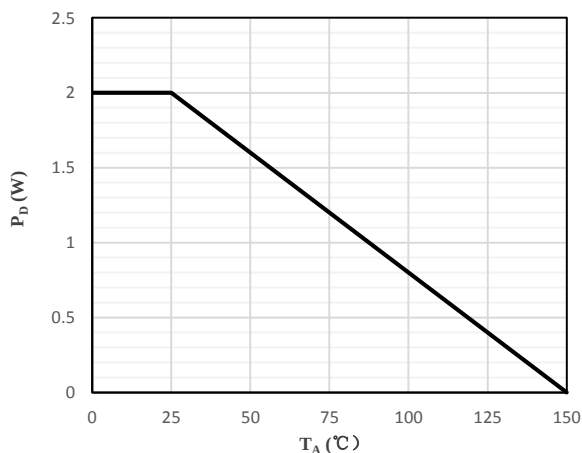


Fig 6 P_D vs. T_A

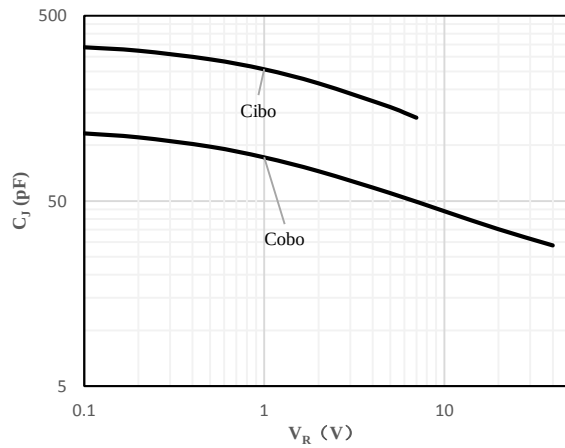
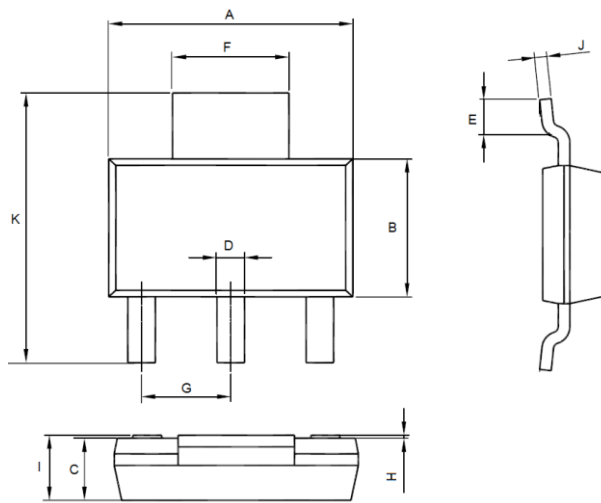


Fig 7 C_J vs. V_R

Package Outline Dimensions (Unit: mm)



SOT-223		
Dimension	Min.	Max.
A	6.10	6.50
B	3.30	3.70
C	1.50	1.70
D	0.66	0.82
E	0.90	1.15
F	2.90	3.10
G	2.20	2.40
H	0.02	0.10
I	1.52	1.80
J	0.20	0.40
K	6.70	7.30

Mounting Pad Layout (Unit: mm)

SOT-223

